Dr. Jae-Hoon Han

Korea Institute of Science and Technology,
Republic of Korea

Jae-Hoon Han was born in Seoul, Republic of Korea, in 1988. He received his B.S., M.S., and Ph.D. degrees in electrical and electronic engineering from the University of Tokyo, Japan, in 2012, 2014, and 2017, respectively. He is currently a research associate in Korea Institute of Science and Technology (KIST). His current research interests include heterogeneous integration for opto-electronic devices, especially for Si photonics. He is also working on device engineering for MOS interface and ferroelectric $HfZrO_2$.